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NE5534, NE5534A, SE5534, SE5534A LOW-NOISE OPERATIONAL AMPLIFIERS

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- **Equivalent Input Noise Voltage** 3.5 nV/√Hz
- Unity-Gain Bandwidth . . . 10 MHz Typ
- Common-Mode Rejection Ratio 100 dB Typ
- High DC Voltage Gain . . . 100 V/mV Typ
- Peak-to-Peak Output Voltage Swing 32 V Typ With $V_{CC+} = \pm 18$ V and $R_L = 600 \Omega$
- High Slew Rate . . . 13 V/µs Typ
- Wide Supply Voltage Range ± 3 V to ± 20 V
- **Low Harmonic Distortion**
- Designed to Be Interchangeable With Signetics NE5534, NE5534A, SE5534, and SE5534A

description

The NE5534, NE5534A, SE5534, and SE5534A are monolithic high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output drive capability, high unitygain and maximum-output-swing bandwidths, low distortion, and high slew rate.

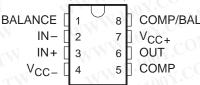
These operational amplifiers are internally compensated for a gain equal to or greater than three. Optimization of the frequency response for various applications can be obtained by use of an external compensation capacitor between COMP and COMP/BAL. The devices feature inputprotection diodes, output short-circuit protection, and offset-voltage nulling capability.

For the NE5534A, a maximum limit is specified for equivalent input noise voltage.

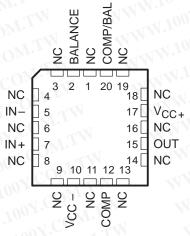
The NE5534 and NE5534A are characterized for operation from 0°C to 70°C. The SE5534 and SE5534A are characterized for operation over the full military temperature range of – 55°C to 125°C.

SE5534, SE5534A . . . JG PACKAGE (TOP VIEW) COMP/BAI 8

NE5534, NE5534A . . . D OR P PACKAGE

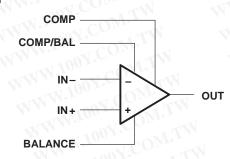


SE5534, SE5534A...FK PACKAGE (TOP VIEW)



NC - No internal connection

symbol



SE5534A FROM TI NOT RECOMMENDED FOR NEW DESIGNS

AVAILABLE OPTIONS

	Via mov	MM 100X.	PACK	AGE	N.1007.		
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CERAMIC (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)		
0°C to 70°C	0° C to 70° C 4 mV		70°C 4 mV NE5534D NE5534AD		N $^{C}\overline{\Omega_{M:I}}$		NE5534P NE5534AP
– 55°C to 125°C			SE5534FK SE5534AFK	SE5534JG SE5534AJG			

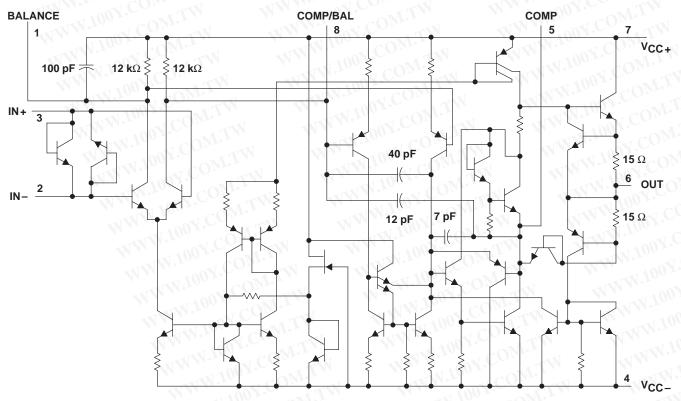
The D package is available taped and reeled. Add the suffix R to the device type (e.g., NE5534DR).

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schematic



All component values shown are nominal.

Pin numbers shown are for D, JG, and P packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC+} (see Note 1)	22 V
Supply voltage, V _{CC} (see Note 1)	
Input voltage either input (see Notes 1 and 2)	
Input current (see Note 3)	±10 mA
Duration of output short circuit (see Note 4)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range: NE5534, NE5534A	0°C to 70°C
SE5534, SE5534A	– 55°C to 125°C
Storage temperature range	– 65°C to 150°C
Case temperature for 60 seconds: FK package	
Lead temperature range 1,6 mm (1/16 inch) from case for 60 seconds: JG pac	kage 300°C
Lead temperature range 1,6 mm (1/16 inch) from case for 10 seconds: D or P	package 260°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
 - 3. Excessive current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs unless some limiting resistance is used.
 - 4. The output may be shorted to ground or to either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.



NE5534, NE5534A, SE5534, SE5534A LOW-NOISE OPERATIONAL AMPLIFIERS

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DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	N/A
FK (see Note 5)	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
P COM	1000 mW	8.0 mW/°C	640 mW	N/A

NOTE 5: For the FK package, power rating and derating factor will vary with actual mounting technique used. The values stated here are believed to be conservative.

recommended operating conditions

M. 100 . COM	COM.	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	N.I.A. M	5	TIVI.	15	V
Supply voltage, V _{CC} _	TW WWW. 100Y. COLITY	- 5		- 15	V

electrical characteristics, V_{CC} \pm = ± 15 V, T_A = $25^{\circ}C$ (unless otherwise noted)

DADAMETER		COM	V.V.V.J	NE55	NE5534, NE5534A		SE5534, SE5534A			UNIT
	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V _{IO}	Input offset voltage	$V_O = 0$, RS = 50 Ω	T _A = 25°C	1007	0.5	4		0.5	2	1007.
			T _A = Full range	1.5	V.CO	5	N	V	3	mV
I	lament affect assuments	V _O = 0	T _A = 25°C	W.In.	20	300	XXI	10	200	nA
IIO	Input offset current		T _A = Full range	TXV.10	Or.	400	L V .		500	
L	land him summed	V _O = 0	T _A = 25°C	- 1	500	1500	IN	400	800	-x1.10
lΒ	Input bias current		T _A = Full range	M.M.	Your	2000	WT		1500	nA
VICR	Common-mode input voltage range	A.Ino. COM.	TW	±12	±13	Y.CO	±12	±13	W	V
.,	Maximum peak-to-peak	M. D. COM	$V_{CC\pm} = \pm 15 \text{ V}$	24	26	M.C.	24	26		144
VO(PP)	output voltage swing	R _L ≥ 600 Ω	$V_{CC\pm} = \pm 18 \text{ V}$	30	32	N.C	30	32		V
Δ	Large-signal differential	$V_{O} = \pm 10 \text{ V},$	T _A = 25°C	25	100	JU -	50	100		V/mV
AVD	voltage amplification	$R_L \ge 600 \Omega$	T _A = Full range	15		1001.	25	JA		
Λ .	Small-signal differential voltage amplification	f = 10 kHz	C _C = 0	W	6	1005	.00	6		V/mV
A _{vd}			C _C = 22 pF		2.2	00	A'CO	2.2	N	
	Maximum-output-swing	$V_0 = \pm 10 \text{ V},$	$C_C = 0$		200	W.Inc	-1 CC	200		kHz
Вом		$V_0 = \pm 10 \text{ V},$	C _C = 22 pF		95	11 IV	11.	95	A	
DOM	bandwidth	$V_{CC\pm} = \pm 18 \text{ V},$ $R_L \ge 600 \Omega,$	$V_O = \pm 14 \text{ V},$ $C_C = 22 \text{ pF}$	LT	70	WW.1	OOY.C	70	TI	
B ₁	Unity-gain bandwidth	C _C = 22 pF,	C _L = 100 pF		10	- TIN	100 .	10	1.1.	MHz
rį	Input resistance	MM	1.17 T	30	100	144	50	100	VI.TV	kΩ
z _o	Output impedance	$A_{VD} = 30 \text{ dB},$ $C_{C} = 22 \text{ pF},$	$R_L \ge 600 \Omega$, $f = 10 \text{ kHz}$	LM	0.3	WW	W.100	0.3	T.MC	Ω
CMRR	Common-mode rejection ratio	$V_O = 0$, $R_S = 50 \Omega$	V _{IC} = V _{ICR} min,	70	100		80	100		dB
ksvr	Supply voltage rejection ratio (ΔV _{CC} /ΔV _{IO})	$V_{CC+}=\pm 9 V to \pm 15 V,$ $V_{O}=0,$	R _S = 50 Ω	80	100		86	100		dB
los	Output short-circuit current	W	AM. CI	77.	38			38		mA
loo	Supply current	$V_{O} = 0$,	T _A = 25°C		4	8		4	6.5	^
ICC	Зирріу сипепі	No load	T _A = Full range						9	mA

 $[\]overline{T}$ All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is $T_A = 0^{\circ}$ C to 70° C for NE5534 and NE5534A and -55° C to 125° C for SE5534 and SE5534A.



NE5534, NE5534A, SE5534, SE5534A LOW-NOISE OPERATIONAL AMPLIFIERS

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operating characteristics, $V_{CC} \pm = \pm 15 \text{ V}$, $T_A = 25^{\circ}\text{C}$

DARIAMETER - N. T.W.		TEST CONDITIONS	SE5534, NE5534	SE5534A, NE5534A	LINUT	
	PARAMETER	TEST CONDITIONS	MIN TYP MAX	MIN TYP MAX	UNIT	
SR	Slew rate at unity gain	CC = 0	13	13 C	V/A	
	Siew rate at unity gain	C _C = 22 pF	6	6	V/μs	
<u> </u>	Rise time	$V_{I} = 50 \text{ mV}, A_{VD} = 1,$ $R_{I} = 600 \Omega, C_{C} = 22 \text{ pF},$	20	20	ns	
	Overshoot factor	$R_L = 600 \Omega$, $C_C = 22 pF$, $C_L = 100 pF$	20%	20%	COM	
t _r	Rise time	$V_{I} = 50 \text{ mV}, A_{VD} = 1,$ $R_{I} = 600 \Omega, C_{C} = 47 \text{ pF},$	50	50	ns	
	Overshoot factor	$R_L = 600 \Omega$, $C_C = 47 pF$, $C_L = 500 pF$	35%	35%	3.0	
٧n	Equivalent input pains valtage	f = 30 Hz	7.TW	5.5 7		
	Equivalent input noise voltage	f = 1 kHz	LOV.CO4	3.5 4.5	nV/√Hz	
	Equipolant input balan aumant	f = 30 Hz	2.5	1.5	pA/√ Hz	
In	Equivalent input noise current	f = 1 kHz	0.6	0.4		
F	Average noise figure	$R_S = 5 \text{ k}\Omega$, $f = 10 \text{ Hz to } 20 \text{ kHz}$	1100Y.	0.9	dB	

TYPICAL CHARACTERISTICS[†]

NORMALIZED INPUT BIAS CURRENT AND INPUT OFFSET CURRENT

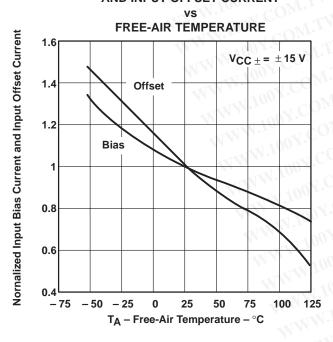


Figure 1

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

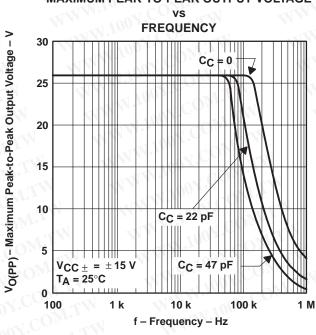


Figure 2

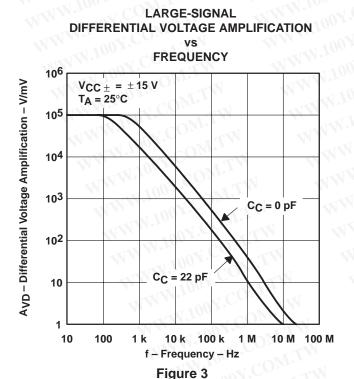
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

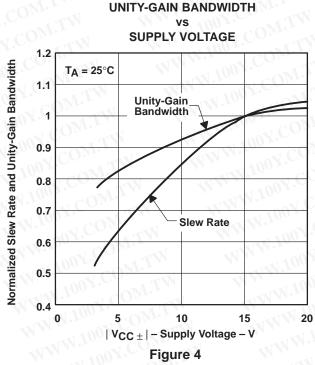


NORMALIZED SLEW RATE AND

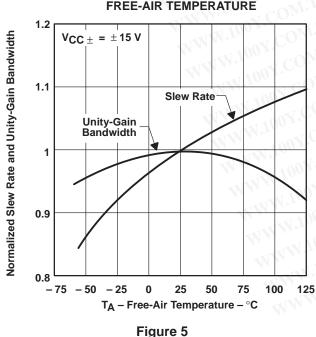
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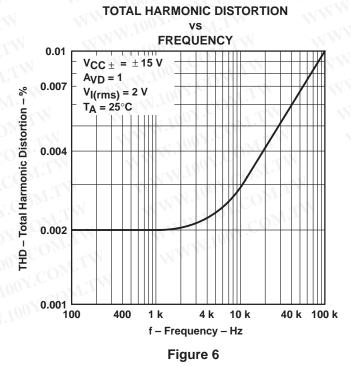
TYPICAL CHARACTERISTICS[†]





NORMALIZED SLEW RATE AND UNITY-GAIN BANDWIDTH vs FREE-AIR TEMPERATURE





† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

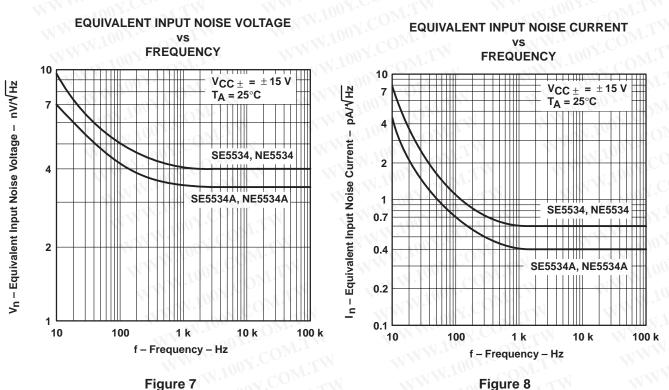


Figure 8

TOTAL EQUIVALENT INPUT NOISE VOLTAGE VS SOURCE RESISTANCE 100 $V_{CC \pm} = \pm 15 V$ 70 Fotal Equivalent Input Noise Voltage – μV T_A = 25°C 40 20 10 7 4 f = 10 Hz to 20 kHz2 1 0.7 0.4 200 Hz to 4 kHz 0.2 0.1 100 10 k 100 k Rs – Source Resistance – Ω

Figure 9

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